MOSFETs Silicon P-Channel MOS (U-MOSVI)

# TJ15P04M3

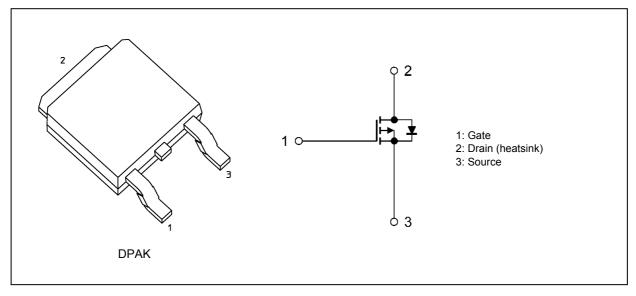
#### 1. Applications

- Motor Drivers
- Power Management Switches

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 28 \text{ m}\Omega \text{ (typ.)} (V_{GS} = -10 \text{ V})$
- (2) Low leakage current:  $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -40 \ V)$
- (3) Enhancement mode:  $V_{th}$  = -0.8 to -2.0 V (V\_{DS} = -10 V,  $I_{D}$  = -0.1 mA)

#### 3. Packaging and Internal Circuit



#### 4. Absolute Maximum Ratings (Note) (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics				Rating	Unit
Drain-source voltage			V <sub>DSS</sub>	-40	V
Gate-source voltage			V <sub>GSS</sub>	±20	
Drain current (DC)	(Note	1)	I <sub>D</sub>	-15	A
Drain current (pulsed)	(Note	1)	I <sub>DP</sub>	-45	
Power dissipation	(T <sub>c</sub> = 25°C)		PD	29	W
Single-pulse avalanche energy	(Note	2)	E <sub>AS</sub>	29	mJ
Single-pulse avalanche current			I <sub>AS</sub>	-15	A
Channel temperature			T <sub>ch</sub>	150	°C
Storage temperature			T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	4.3	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V<sub>DD</sub> = -32 V, T<sub>ch</sub> = 25°C (initial), L = 100  $\mu$ H, R<sub>G</sub> = 25  $\Omega$ , I<sub>AS</sub> = -15 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

#### 6. Electrical Characteristics

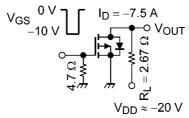
#### 6.1. Static Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V	_	_	±0.1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = -40 V, V <sub>GS</sub> = 0 V	-	—	-10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = -10 mA, V <sub>GS</sub> = 0 V	-40	_	_	V
Drain-source breakdown voltage (Note 3)	V <sub>(BR)DSX</sub>	I <sub>D</sub> = -10 mA, V <sub>GS</sub> = 10 V	-30	—	—	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -0.1 mA	-0.8	_	-2.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -7.5 A	_	37	48	mΩ
		V <sub>GS</sub> = -10 V, I <sub>D</sub> = -7.5 A	_	28	36	

Note 3: If a reverse bias is applied between gate and source, this device enters V<sub>(BR)DSX</sub> mode. Note that the drainsource breakdown voltage is lowered in this mode.

#### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	1100	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	130	—	
Output capacitance	C <sub>oss</sub>		_	170	_	
Switching time (rise time)	tr	See Figure 6.2.1.	_	11	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	19	—	
Switching time (fall time)	t <sub>f</sub>		_	42	—	
Switching time (turn-off time)	t <sub>off</sub>		_	170		



#### Duty $\leq$ 1%, $t_W^{}=$ 10 $\mu s$

Fig. 6.2.1 Switching Time Test Circuit

#### 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

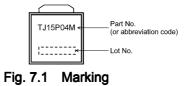
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx$ -32 V, $V_{GS}$ = -10 V, $I_D$ = -15 A	—	26	—	nC
Gate-source charge 1	Q <sub>gs1</sub>		_	6.7	_	
Gate-drain charge	Q <sub>gd</sub>			2.5	_	

#### 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

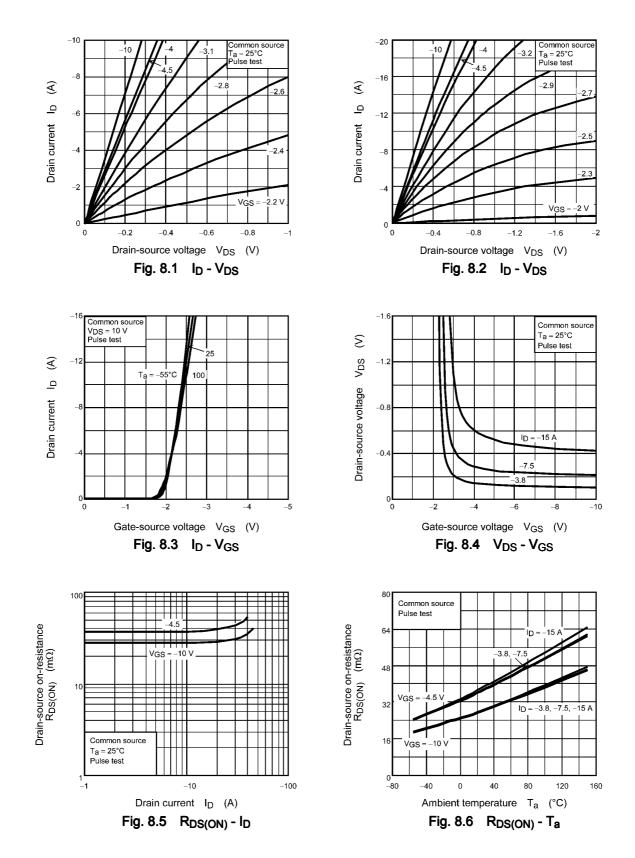
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 4)	I <sub>DRP</sub>	—	_	—	-45	А
Diode forward voltage	V <sub>DSF</sub>	I <sub>DR</sub> = -15 A, V <sub>GS</sub> = 0 V	_	_	1.2	V

Note 4: Ensure that the channel temperature does not exceed 150°C.

### 7. Marking



### 8. Characteristics Curves (Note)



-2

-1.6 

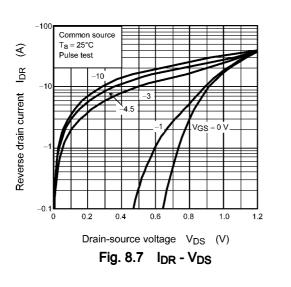
-1.2

-0.8

-0.4

Common source

S



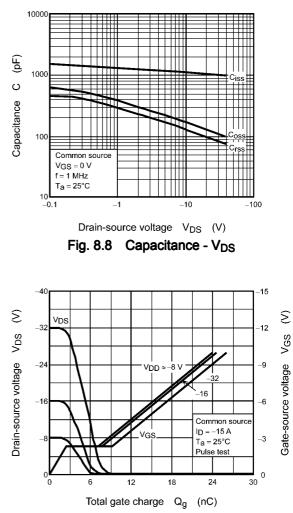
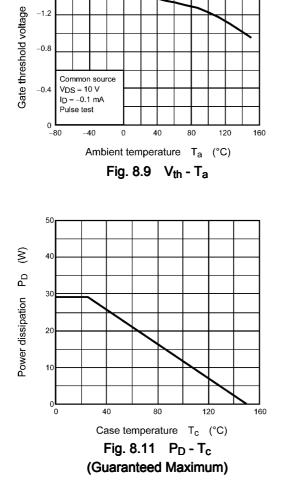


Fig. 8.10 Dynamic Input/Output Characteristics



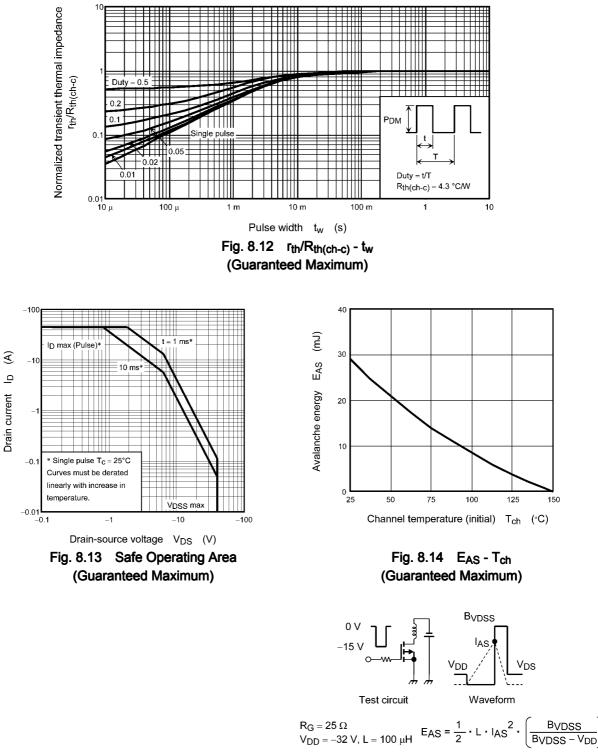
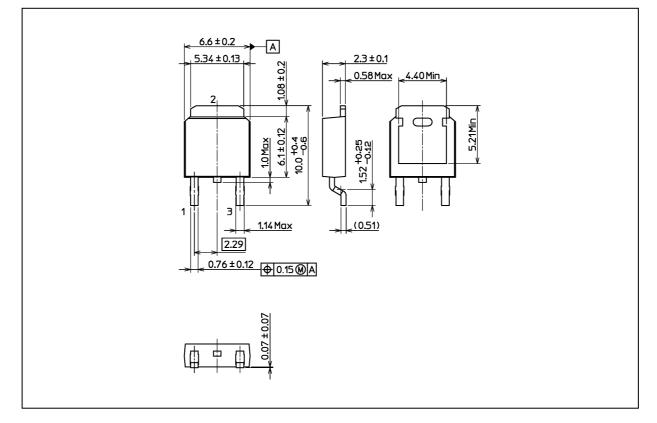


Fig. 8.15 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### Package Dimensions

Unit: mm



#### Weight: 0.36 g (typ.)

	Package Name(s)
TOSHIBA: 2-7K1S	
Nickname: DPAK	

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